

50 V, 100 mA PNP resistor-equipped transistor; R1 = 4.7 k Ω , R2 = 47 k Ω

23 January 2024

Product data sheet

1. General description

PNP Resistor-Equipped Transistor (RET) in an ultra small SOT883 (SC-101) Surface-Mounted Device (SMD) plastic package.

NPN complement: PDTC143ZM

2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- · Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified

3. Applications

- · Digital application in automotive and industrial segments
- Cost-saving alternative for BC847/857 series in digital applications
- · Controlling IC inputs
- · Switching loads

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-50	V
Io	output current			-	-	-100	mA
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	

[1] See section "Test information" for resistor calculation and test conditions



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	3	
2	GND	ground (emitter)		
3	0	output (collector)	Transparent top view DFN1006-3 (SOT883)	R1 R2 GND sym003

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage					
	Name	Description	Version				
PDTA143ZM		plastic, leadless ultra small package; 3 terminals; 0.35 mm pitch; 1 mm x 0.6 mm x 0.48 mm body	<u>SOT883</u>				

7. Marking

Table 4. Marking codes

Type number	Marking code
PDTA143ZM	DP

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

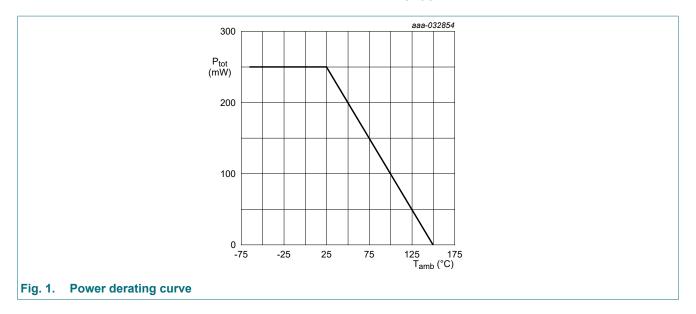
Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-50	V
V_{CEO}	collector-emitter voltage	open base		-	-50	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
V _I	input voltage			-30	5	V
Io	output current			-	-100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1] [2]	-	250	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Reflow soldering is the only recommended soldering method.

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^[2] Device mounted on an FR4 Printed-Circuit Board (PCB) with 70 µm copper strip line, standard footprint.

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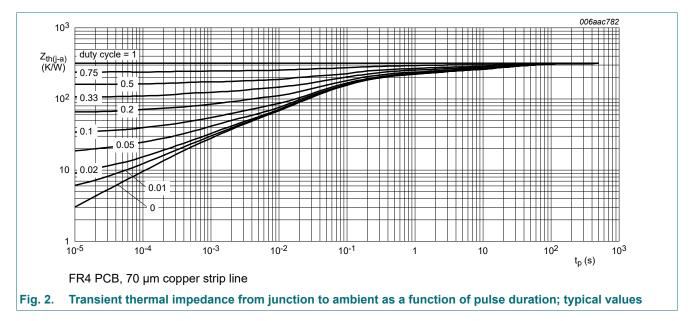


9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
· -ui(y-a)	thermal resistance from junction to ambient		[1] [2]	-	-	500	K/W

- [1] Reflow soldering is the only recommended soldering method.
- [2] Device mounted on an FR4 PCB with 70 μm copper strip line, standard footprint.



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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{(BR)CBO}	collector-base breakdown voltage	$I_C = -100 \mu A; I_E = 0 A; T_{amb} = 25 °C$		-50	-	-	V
V _{(BR)CEO}	collector-emitter breakdown voltage	$I_C = -2 \text{ mA}; I_B = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-50	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	C = 0 A; I _E = -100 μA; T _{amb} = 25 °C		-5	-	-	V
I _{CBO}	collector-base cut-off current	V _{CB} = -50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	-100	nA
I _{CEO}	collector-emitter cut-off	V _{CE} = -30 V; I _B = 0 A; T _{amb} = 25 °C		-	-	-1	μA
	current	V _{CE} = -30 V; I _B = 0 A; T _j = 150 °C		-	-	-5	μA
I _{EBO}	emitter-base cut-off current	V _{EB} = -5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	-170	μA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -10 mA; T _{amb} = 25 °C		100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	-100	mV
V _{I(off)}	off-state input voltage	V _{CE} = -5 V; I _C = -100 μA; T _{amb} = 25 °C		-	-0.6	-0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = -0.3 V; I_{C} = -5 mA; T_{amb} = 25 °C		-1.3	-0.9	-	V
R1	bias resistor 1 (input)	T _{amb} = 25 °C	[1]	3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		[1]	8	10	12	
C _c	collector capacitance	V_{CB} = -10 V; I_{E} = 0 A; i_{e} = 0 A; f = 1 MHz; T_{amb} = 25 °C		-	-	3	pF
f _T	transition frequency	V_{CE} = -5 V; I_{C} = -10 mA; f = 100 MHz; T_{amb} = 25 °C	[2]	-	180	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions
- [2] Characteristics of built-in transistor

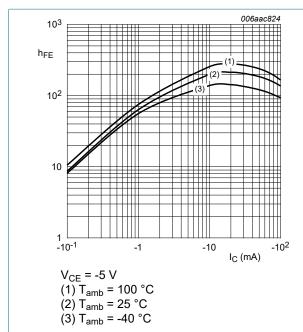
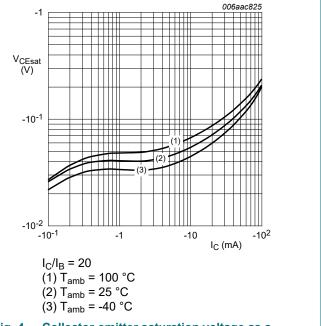
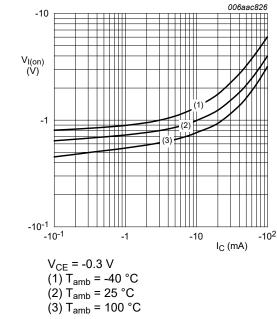


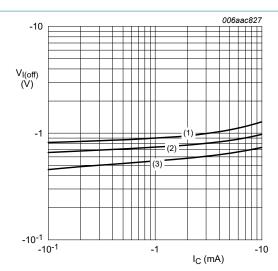
Fig. 3. DC current gain as a function of collector current; typical values



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V_{CE} = -5 V (1) T_{amb} = -40 °C (2) T_{amb} = 25 °C

(3) $T_{amb} = 100 \, ^{\circ}C$

Off-state input voltage as a function of collector current; typical values

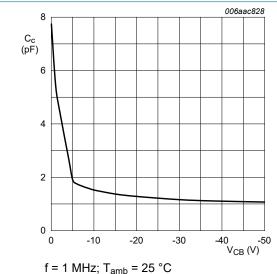
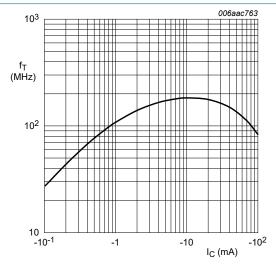


Fig. 7. Collector capacitance as a function of collector- Fig. 8. base voltage; typical values



 V_{CE} = -5 V; T_{amb} = 25 °C

Transition frequency as a function of collector current; typical values of built-in transistor

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11. Test information

Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

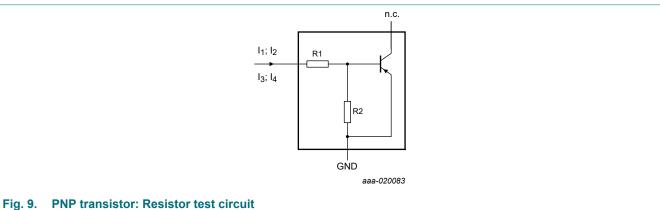
Resistor calculation

· Calculation of bias resistor 1 (R1)

$$R_{I} = \frac{V(I_{2}) - V(I_{1})}{I_{2} - I_{1}}$$

· Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I4) - V(I3)}{R1 \cdot (I4 - I3)} - 1$$



Resistor test conditions

Table 8. Resistor test conditions

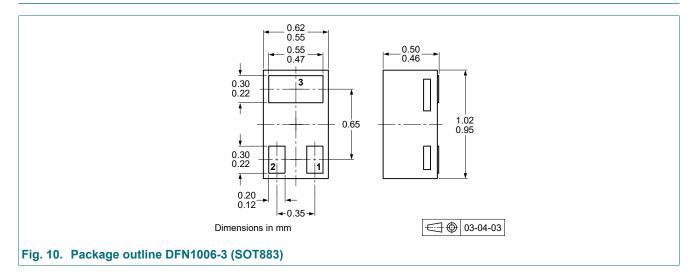
Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I ₁	l ₂	l ₃	14
PDTA143ZM	4.7	47	-90 µA	-140 µA	55 µA	105 μΑ

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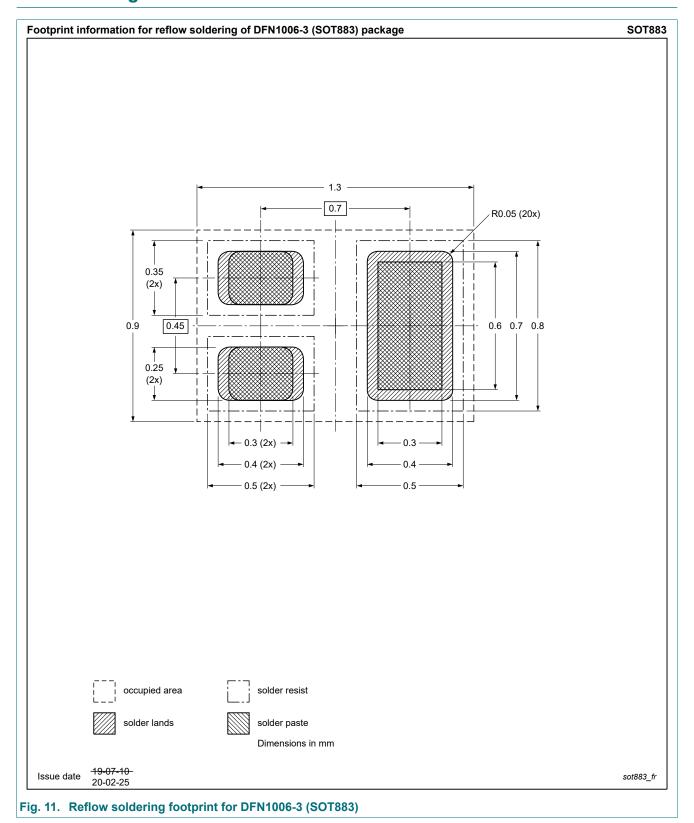
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12. Package outline



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13. Soldering



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14. Revision history

Table 9. Revision history

Table 6. Reviolet metery								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PDTA143ZM v.8	20240123	Product data sheet	-	PDTA143Z_SER v.7				
Modification:	•	sheet reduced to single type da mation removed.	ita sheet.					
PDTA143Z_SER v.7	20111205	Product data sheet	-	PDTA143Z_SERIES v.6				
PDTA143Z_SERIES v.6	20040805	Product data sheet	-	PDTA143Z_SERIES v.5				
PDTA143Z_SERIES v.5	20030908	Product specification	-	PDTA143Z_SERIES v.4				
PDTA143Z_SERIES v.4	20030410	Product specification	-	-				

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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